



COPY OF PAPERS
ORIGINALLY FILED
- 1 -

Docket No. 0756-2293

UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of

Tatsuya ARAO et al.

Serial No. 09/826,416

Filed: April 5, 2001

For: SEMICONDUCTOR DEVICE AND

MANUFACTURING METHOD

THEREOF

) Art Unit: 2811

) Examiner: T. Tran

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with
The United States Postal Service with sufficient postage as First
Class Mail in an envelope addressed to: Commissioner for Patents,
Washington, D.C. 20231, on 7-10-02

AMENDMENT

Honorable Commissioner of Patents

Washington, D.C. 20231

Sir:

In response to the Office Action dated April 10, 2002 please amend the above-
identified application as follows:

IN THE CLAIMS:

Please cancel claims 1, 3, 5-11, and 25 and amend claims 23 and 28 as follows:

B¹
23. (Amended) A semiconductor device according to claim 2, wherein the third
conductive film comprises at least one material selected from the group consisting of
Ta, Ti, W and an alloy thereof.

B²
28. (Amended) A semiconductor device according to claim 4, wherein the gate
electrode comprises at least one material selected from the group consisting of Ta, Ti,
W, and an alloy thereof.

Please add new claims 30-42 as follows:

B³
P.C.
-- 30. A semiconductor device comprising:

07/18/2002 SHINASSI 00000088 09826416

54.00 OP
168.00 OP

01 FC:103
02 FC:102